Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

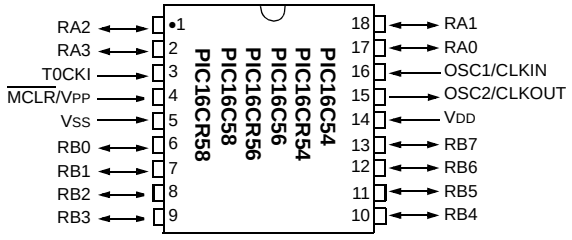
"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

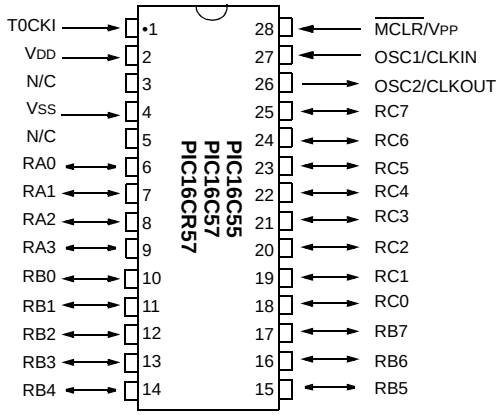
Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	10MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	20
Program Memory Size	3KB (2K x 12)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	72 x 8
Voltage - Supply (Vcc/Vdd)	4.5V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Through Hole
Package / Case	28-DIP (0.600", 15.24mm)
Supplier Device Package	28-PDIP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c57-10-p

Pin Diagrams

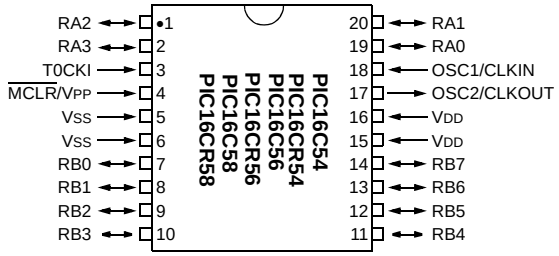
PDIP, SOIC, Windowed CERDIP



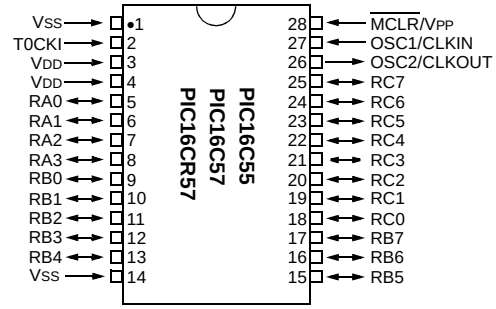
PDIP, SOIC, Windowed CERDIP



SSOP



SSOP



Device Differences

Device	Voltage Range	Oscillator Selection (Program)	Oscillator	Process Technology (Microns)	ROM Equivalent	$\overline{\text{MCLR}}$ Filter
PIC16C54	2.5-6.25	Factory	See **Note 1**	1.2	PIC16CR54A	No
PIC16C54A	2.0-6.25	User	See **Note 1**	0.9	—	No
PIC16C54C	2.5-5.5	User	See **Note 1**	0.7	PIC16CR54C	Yes
PIC16C55	2.5-6.25	Factory	See **Note 1**	1.7	—	No
PIC16C55A	2.5-5.5	User	See **Note 1**	0.7	—	Yes
PIC16C56	2.5-6.25	Factory	See **Note 1**	1.7	—	No
PIC16C56A	2.5-5.5	User	See **Note 1**	0.7	PIC16CR56A	Yes
PIC16C57	2.5-6.25	Factory	See **Note 1**	1.2	—	No
PIC16C57C	2.5-5.5	User	See **Note 1**	0.7	PIC16CR57C	Yes
PIC16C58B	2.5-5.5	User	See **Note 1**	0.7	PIC16CR58B	Yes
PIC16CR54A	2.5-6.25	Factory	See **Note 1**	1.2	N/A	Yes
PIC16CR54C	2.5-5.5	Factory	See **Note 1**	0.7	N/A	Yes
PIC16CR56A	2.5-5.5	Factory	See **Note 1**	0.7	N/A	Yes
PIC16CR57C	2.5-5.5	Factory	See **Note 1**	0.7	N/A	Yes
PIC16CR58B	2.5-5.5	Factory	See **Note 1**	0.7	N/A	Yes

Note 1: If you change from this device to another device, please verify oscillator characteristics in your application.

Note: The table shown above shows the generic names of the PIC16C5X devices. For device varieties, please refer to Section 2.0.

 © 1997-2013 Microchip Technology Inc.

8-Bit EPROM/ROM-Based CMOS Microcontrollers

1.0 GENERAL DESCRIPTION

The PIC16C5X from Microchip Technology is a family of low cost, high performance, 8-bit fully static, EPROM/ROM-based CMOS microcontrollers. It employs a RISC architecture with only 33 single word/single cycle instructions. All instructions are single cycle except for program branches which take two cycles. The PIC16C5X delivers performance in an order of magnitude higher than its competitors in the same price category. The 12-bit wide instructions are highly symmetrical resulting in 2:1 code compression over other 8-bit microcontrollers in its class. The easy to use and easy to remember instruction set reduces development time significantly.

The PIC16C5X products are equipped with special features that reduce system cost and power requirements. The Power-on Reset (POR) and Device Reset Timer (DRT) eliminate the need for external RESET circuitry. There are four oscillator configurations to choose from, including the power saving LP (Low Power) oscillator and cost saving RC oscillator. Power saving SLEEP mode, Watchdog Timer and Code Protection features improve system cost, power and reliability.

The UV erasable CERDIP packaged versions are ideal for code development, while the cost effective One Time Programmable (OTP) versions are suitable for production in any volume. The customer can take full advantage of Microchip's price leadership in OTP microcontrollers, while benefiting from the OTP's flexibility.

The PIC16C5X products are supported by a full featured macro assembler, a software simulator, an in-circuit emulator, a low cost development programmer and a full featured programmer. All the tools are supported on IBM® PC and compatible machines.

1.1 Applications

The PIC16C5X series fits perfectly in applications ranging from high speed automotive and appliance motor control to low power remote transmitters/receivers, pointing devices and telecom processors. The EPROM technology makes customizing application programs (transmitter codes, motor speeds, receiver frequencies, etc.) extremely fast and convenient. The small footprint packages, for through hole or surface mounting, make this microcontroller series perfect for applications with space limitations. Low cost, low power, high performance ease of use and I/O flexibility make the PIC16C5X series very versatile even in areas where no microcontroller use has been considered before (e.g., timer functions, replacement of "glue" logic in larger systems, co-processor applications).

6.4 OPTION Register

The OPTION Register is a 6-bit wide, write-only register which contains various control bits to configure the Timer0/WDT prescaler and Timer0.

By executing the `OPTION` instruction, the contents of the W Register will be transferred to the OPTION Register. A RESET sets the OPTION<5:0> bits.

REGISTER 6-2: OPTION REGISTER

U-0	U-0	W-1	W-1	W-1	W-1	W-1	W-1
—	—	T0CS	TOSE	PSA	PS2	PS1	PS0
bit 7							bit 0

bit 7-6: **Unimplemented**: Read as '0'

bit 5: **T0CS**: Timer0 clock source select bit
1 = Transition on T0CKI pin
0 = Internal instruction cycle clock (CLKOUT)

bit 4: **T0SE**: Timer0 source edge select bit
1 = Increment on high-to-low transition on T0CKI pin
0 = Increment on low-to-high transition on T0CKI pin

bit 3: **PSA**: Prescaler assignment bit
1 = Prescaler assigned to the WDT
0 = Prescaler assigned to Timer0

bit 2-0: **PS<2:0>**: Prescaler rate select bits

Bit Value	Timer0 Rate	WDT Rate
000	1 : 2	1 : 1
001	1 : 4	1 : 2
010	1 : 8	1 : 4
011	1 : 16	1 : 8
100	1 : 32	1 : 16
101	1 : 64	1 : 32
110	1 : 128	1 : 64
111	1 : 256	1 : 128

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'	
-n = Value at POR	1 = bit is set	0 = bit is cleared	x = bit is unknown

 © 1997-2013 Microchip Technology Inc.

TABLE 10-2: INSTRUCTION SET SUMMARY

Mnemonic, Operands		Description	Cycles	12-Bit Opcode MSb	12-Bit Opcode LSb	Status Affected	Notes
ADDWF	f,d	Add W and f	1	0001 11df ffff		C,DC,Z	1,2,4
ANDWF	f,d	AND W with f	1	0001 01df ffff		Z	2,4
CLRF	f	Clear f	1	0000 011f ffff		Z	4
CLRW	–	Clear W	1	0000 0100 0000		Z	
COMF	f, d	Complement f	1	0010 01df ffff		Z	
DECF	f, d	Decrement f	1	0000 11df ffff		Z	2,4
DECFSZ	f, d	Decrement f, Skip if 0	1(2)	0010 11df ffff		None	2,4
INCF	f, d	Increment f	1	0010 10df ffff		Z	2,4
INCFSZ	f, d	Increment f, Skip if 0	1(2)	0011 11df ffff		None	2,4
IORWF	f, d	Inclusive OR W with f	1	0001 00df ffff		Z	2,4
MOVF	f, d	Move f	1	0010 00df ffff		Z	2,4
MOVWF	f	Move W to f	1	0000 001f ffff		None	1,4
NOP	–	No Operation	1	0000 0000 0000		None	
RLF	f, d	Rotate left f through Carry	1	0011 01df ffff		C	2,4
RRF	f, d	Rotate right f through Carry	1	0011 00df ffff		C	2,4
SUBWF	f, d	Subtract W from f	1	0000 10df ffff		C,DC,Z	1,2,4
SWAPF	f, d	Swap f	1	0011 10df ffff		None	2,4
XORWF	f, d	Exclusive OR W with f	1	0001 10df ffff		Z	2,4
BIT-ORIENTED FILE REGISTER OPERATIONS							
BCF	f, b	Bit Clear f	1	0100 bbbf ffff		None	2,4
BSF	f, b	Bit Set f	1	0101 bbbf ffff		None	2,4
BTFSC	f, b	Bit Test f, Skip if Clear	1 (2)	0110 bbbf ffff		None	
BTFSS	f, b	Bit Test f, Skip if Set	1 (2)	0111 bbbf ffff		None	
LITERAL AND CONTROL OPERATIONS							
ANDLW	k	AND literal with W	1	1110 kkkk kkkk		Z	
CALL	k	Call subroutine	2	1001 kkkk kkkk		None	1
CLRWDT	k	Clear Watchdog Timer	1	0000 0000 0100		$\overline{TO}$, $\overline{PD}$	
GOTO	k	Unconditional branch	2	101k kkkk kkkk		None	
IORLW	k	Inclusive OR Literal with W	1	1101 kkkk kkkk		Z	
MOVLW	k	Move Literal to W	1	1100 kkkk kkkk		None	
OPTION	k	Load OPTION register	1	0000 0000 0010		None	
RETLW	k	Return, place Literal in W	2	1000 kkkk kkkk		None	
SLEEP	–	Go into standby mode	1	0000 0000 0011		$\overline{TO}$, $\overline{PD}$	
TRIS	f	Load TRIS register	1	0000 0000 0fff		None	3
XORLW	k	Exclusive OR Literal to W	1	1111 kkkk kkkk		Z	

Note 1: The 9th bit of the program counter will be forced to a '0' by any instruction that writes to the PC except for GOTO (see Section 6.5 for more on program counter).

2: When an I/O register is modified as a function of itself (e.g. MOVF PORTB, 1), the value used will be that value present on the pins themselves. For example, if the data latch is '1' for a pin configured as input and is driven low by an external device, the data will be written back with a '0'.

3: The instruction TRIS f, where f = 5, 6 or 7 causes the contents of the W register to be written to the tristate latches of PORTA, B or C respectively. A '1' forces the pin to a hi-impedance state and disables the output buffers.

4: If this instruction is executed on the TMR0 register (and, where applicable, d = 1), the prescaler will be cleared (if assigned to TMR0).

 © 1997-2013 Microchip Technology Inc.

BSF **Bit Set f**

Syntax: [*label*] BSF f,b

Operands: $0 \le f \le 31$
$0 \le b \le 7$

Operation: $1 \rightarrow (f<b>)$

Status Affected: None

Encoding:

0101	bbbf	ffff

Description: Bit 'b' in register 'f' is set.

Words: 1

Cycles: 1

Example:
```
BSF     FLAG_REG,    7
```
Before Instruction
FLAG_REG = 0x0A
After Instruction
FLAG_REG = 0x8A

BTFSC **Bit Test f, Skip if Clear**

Syntax: [*label*] BTFSC f,b

Operands: $0 \le f \le 31$
$0 \le b \le 7$

Operation: skip if (f<b>) = 0

Status Affected: None

Encoding:

0110	bbbf	ffff

Description: If bit 'b' in register 'f' is 0 then the next instruction is skipped.
If bit 'b' is 0 then the next instruction fetched during the current instruction execution is discarded, and a `NOP` is executed instead, making this a 2-cycle instruction.

Words: 1

Cycles: 1(2)

Example:
```
HERE    BTFSC   FLAG,1
FALSE   GOTO    PROCESS_CODE
TRUE    •
        •
        •
```
Before Instruction
PC = address `(HERE)`
After Instruction
if FLAG<1> = 0,
PC = address `(TRUE)`;
if FLAG<1> = 1,
PC = address `(FALSE)`

BTFSS **Bit Test f, Skip if Set**

Syntax: [*label*] BTFSS f,b

Operands: $0 \le f \le 31$
$0 \le b < 7$

Operation: skip if (f<b>) = 1

Status Affected: None

Encoding:

0111	bbbf	ffff

Description: If bit 'b' in register 'f' is '1' then the next instruction is skipped.
If bit 'b' is '1', then the next instruction fetched during the current instruction execution, is discarded and a `NOP` is executed instead, making this a 2-cycle instruction.

Words: 1

Cycles: 1(2)

Example:
```
HERE    BTFSS   FLAG,1
FALSE   GOTO    PROCESS_CODE
TRUE    •
        •
        •
```
Before Instruction
PC = address `(HERE)`
After Instruction
If FLAG<1> = 0,
PC = address `(FALSE)`;
if FLAG<1> = 1,
PC = address `(TRUE)`

 © 1997-2013 Microchip Technology Inc.

12.1 DC Characteristics: PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)

PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)			**Standard Operating Conditions (unless otherwise specified)** Operating Temperature 0°C ≤ TA ≤ +70°C for commercial				
Param No.	**Symbol**	**Characteristic/Device**	**Min**	**Typ†**	**Max**	**Units**	**Conditions**
D001	VDD	**Supply Voltage**					
		PIC16C5X-RC	3.0	—	6.25	V	
		PIC16C5X-XT	3.0	—	6.25	V	
		PIC16C5X-10	4.5	—	5.5	V	
		PIC16C5X-HS	4.5	—	5.5	V	
		PIC16C5X-LP	2.5	—	6.25	V	
D002	VDR	**RAM Data Retention Voltage(1)**		1.5*	—	V	Device in SLEEP Mode
D003	VPOR	**VDD Start Voltage** to ensure Power-on Reset		VSS	—	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	**VDD Rise Rate** to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 5.1 for details on Power-on Reset
D010	IDD	**Supply Current(2)**					
		PIC16C5X-RC(3)	—	1.8	3.3	mA	FOSC = 4 MHz, VDD = 5.5V
		PIC16C5X-XT	—	1.8	3.3	mA	FOSC = 4 MHz, VDD = 5.5V
		PIC16C5X-10	—	4.8	10	mA	FOSC = 10 MHz, VDD = 5.5V
		PIC16C5X-HS	—	4.8	10	mA	FOSC = 10 MHz, VDD = 5.5V
		PIC16C5X-HS	—	9.0	20	mA	FOSC = 20 MHz, VDD = 5.5V
		PIC16C5X-LP	—	15	32	µA	FOSC = 32 kHz, VDD = 3.0V, WDT disabled
D020	IPD	**Power-down Current(2)**	—	4.0	12	µA	VDD = 3.0V, WDT enabled
			—	0.6	9	µA	VDD = 3.0V, WDT disabled

* These parameters are characterized but not tested.

† Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, $\overline{\text{MCLR}}$ = VDD; WDT enabled/disabled as specified.

b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.

3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

 © 1997-2013 Microchip Technology Inc.

12.2 DC Characteristics: PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)

PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)			Standard Operating Conditions (unless otherwise specified) Operating Temperature –40°C ≤ TA ≤ +85°C for industrial				
Param No.	**Symbol**	**Characteristic/Device**	**Min**	**Typ†**	**Max**	**Units**	**Conditions**
D001	VDD	**Supply Voltage**					
		PIC16C5X-RCI	3.0	—	6.25	V	
		PIC16C5X-XTI	3.0	—	6.25	V	
		PIC16C5X-10I	4.5	—	5.5	V	
		PIC16C5X-HSI	4.5	—	5.5	V	
		PIC16C5X-LPI	2.5	—	6.25	V	
D002	VDR	**RAM Data Retention Voltage(1)**	—	1.5*	—	V	Device in SLEEP mode
D003	VPOR	**VDD Start Voltage** to ensure Power-on Reset	—	VSS	—	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	**VDD Rise Rate** to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 5.1 for details on Power-on Reset
D010	IDD	**Supply Current(2)**					
		PIC16C5X-RCI(3)	—	1.8	3.3	mA	FOSC = 4 MHz, VDD = 5.5V
		PIC16C5X-XTI	—	1.8	3.3	mA	FOSC = 4 MHz, VDD = 5.5V
		PIC16C5X-10I	—	4.8	10	mA	FOSC = 10 MHz, VDD = 5.5V
		PIC16C5X-HSI	—	4.8	10	mA	FOSC = 10 MHz, VDD = 5.5V
		PIC16C5X-HSI	—	9.0	20	mA	FOSC = 20 MHz, VDD = 5.5V
		PIC16C5X-LPI	—	15	40	µA	FOSC = 32 kHz, VDD = 3.0V, WDT disabled
D020	IPD	**Power-down Current(2)**	—	4.0	14	µA	VDD = 3.0V, WDT enabled
			—	0.6	12	µA	VDD = 3.0V, WDT disabled

* These parameters are characterized but not tested.

† Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, $\overline{\text{MCLR}}$ = VDD; WDT enabled/disabled as specified.

b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.

3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

12.5 DC Characteristics: PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)

DC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature –40°C ≤ TA ≤ +125°C for extended				
Param No.	**Symbol**	**Characteristic**	**Min**	**Typ†**	**Max**	**Units**	**Conditions**
D030	VIL	**Input Low Voltage**					
		I/O ports	Vss	—	0.15 VDD	V	Pin at hi-impedance
		MCLR (Schmitt Trigger)	Vss	—	0.15 VDD	V	
		T0CKI (Schmitt Trigger)	Vss	—	0.15 VDD	V	
		OSC1 (Schmitt Trigger)	Vss	—	0.15 VDD	V	PIC16C5X-RC only(3)
		OSC1 (Schmitt Trigger)	Vss	—	0.3 VDD	V	PIC16C5X-XT, 10, HS, LP
D040	VIH	**Input High Voltage**					
		I/O ports	0.45 VDD	—	VDD	V	For all VDD(4)
		I/O ports	2.0	—	VDD	V	4.0V < VDD ≤ 5.5V(4)
		I/O ports	0.36 VDD	—	VDD	V	VDD > 5.5 V
		MCLR (Schmitt Trigger)	0.85 VDD	—	VDD	V	
		T0CKI (Schmitt Trigger)	0.85 VDD	—	VDD	V	
		OSC1 (Schmitt Trigger)	0.85 VDD	—	VDD	V	PIC16C5X-RC only(3)
		OSC1 (Schmitt Trigger)	0.7 VDD	—	VDD	V	PIC16C5X-XT, 10, HS, LP
D050	VHYS	**Hysteresis of Schmitt Trigger inputs**	0.15 VDD*	—	—	V	
D060	IIL	**Input Leakage Current (1,2)**					**For VDD ≤ 5.5 V:**
		I/O ports	–1	0.5	+1	µA	VSS ≤ VPIN ≤ VDD, pin at hi-impedance
		MCLR	–5	—	—	µA	VPIN = VSS + 0.25V
		MCLR	—	0.5	+5	µA	VPIN = VDD
		T0CKI	–3	0.5	+3	µA	VSS ≤ VPIN ≤ VDD
		OSC1	–3	0.5	+3	µA	VSS ≤ VPIN ≤ VDD, PIC16C5X-XT, 10, HS, LP
D080	VOL	**Output Low Voltage**					
		I/O ports	—	—	0.6	V	IOL = 8.7 mA, VDD = 4.5V
		OSC2/CLKOUT	—	—	0.6	V	IOL = 1.6 mA, VDD = 4.5V, PIC16C5X-RC
D090	VOH	**Output High Voltage(2)**					
		I/O ports	VDD – 0.7	—	—	V	IOH = –5.4 mA, VDD = 4.5V
		OSC2/CLKOUT	VDD – 0.7	—	—	V	IOH = –1.0 mA, VDD = 4.5V, PIC16C5X-RC

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the $\overline{\text{MCLR}}$/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

2: Negative current is defined as coming out of the pin.

3: For PIC16C5X-RC devices, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

4: The user may use the better of the two specifications.

 © 1997-2013 Microchip Technology Inc.

12.7 Timing Diagrams and Specifications

FIGURE 12-2: EXTERNAL CLOCK TIMING - PIC16C54/55/56/57

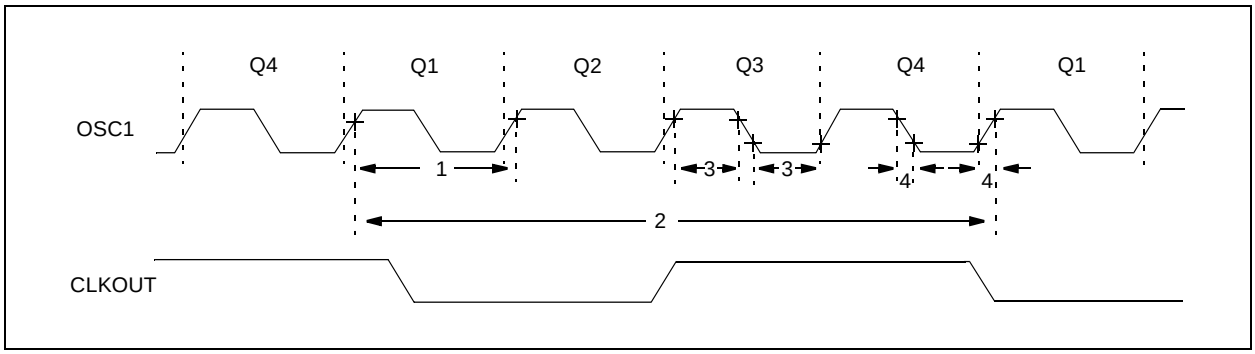


TABLE 12-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54/55/56/57

AC Characteristics		Standard Operating Conditions (unless otherwise specified) Operating Temperature 0°C ≤ TA ≤ +70°C for commercial –40°C ≤ TA ≤ +85°C for industrial –40°C ≤ TA ≤ +125°C for extended					
Param No.	**Symbol**	**Characteristic**	**Min**	**Typ†**	**Max**	**Units**	**Conditions**
1A	FOSC	External CLKIN Frequency(1)	DC	—	4.0	MHz	XT OSC mode
			DC	—	10	MHz	10 MHz mode
			DC	—	20	MHz	HS OSC mode (Comm/Ind)
			DC	—	16	MHz	HS OSC mode (Ext)
			DC	—	40	kHz	LP OSC mode
		Oscillator Frequency(1)	DC	—	4.0	MHz	RC OSC mode
			0.1	—	4.0	MHz	XT OSC mode
			4.0	—	10	MHz	10 MHz mode
			4.0	—	20	MHz	HS OSC mode (Comm/Ind)
			4.0	—	16	MHz	HS OSC mode (Ext)
			DC	—	40	kHz	LP OSC mode

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.
When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

 © 1997-2013 Microchip Technology Inc.

15.2 DC Characteristics: PIC16C54A-04E, 10E, 20E (Extended) PIC16LC54A-04E (Extended)

PIC16LC54A-04E (Extended)			**Standard Operating Conditions (unless otherwise specified)** Operating Temperature –40°C ≤ TA ≤ +125°C for extended				
PIC16C54A-04E, 10E, 20E (Extended)			**Standard Operating Conditions (unless otherwise specified)** Operating Temperature –40°C ≤ TA ≤ +125°C for extended				
Param No.	**Symbol**	**Characteristic**	**Min**	**Typ†**	**Max**	**Units**	**Conditions**
	VDD	**Supply Voltage**					
D001		PIC16LC54A	3.0 2.5	— —	6.25 6.25	V V	XT and RC modes LP mode
D001A		PIC16C54A	3.5 4.5	— —	5.5 5.5	V V	RC and XT modes HS mode
D002	VDR	**RAM Data Retention Voltage(1)**	—	1.5*	—	V	Device in SLEEP mode
D003	VPOR	**VDD Start Voltage** to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	**VDD Rise Rate** to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 5.1 for details on Power-on Reset
	IDD	**Supply Current(2)**					
D010		PIC16LC54A	—	0.5	25	mA	FOSC = 4.0 MHz, VDD = 5.5V, RC(3) and XT modes
			—	11	27	µA	FOSC = 32 kHz, VDD = 2.5V, LP mode, Commercial
			—	11	35	µA	FOSC = 32 kHz, VDD = 2.5V, LP mode, Industrial
			—	11	37	µA	FOSC = 32 kHz, VDD = 2.5V, LP mode, Extended
D010A		PIC16C54A	—	1.8	3.3	mA	FOSC = 4.0 MHz, VDD = 5.5V, RC(3) and XT modes
			—	4.8	10	mA	FOSC = 10 MHz, VDD = 5.5V, HS mode
			—	9.0	20	mA	FOSC = 20 MHz, VDD = 5.5V, HS mode

Legend: Rows with standard voltage device data only are shaded for improved readability.

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, $\overline{MCLR}$ = VDD; WDT enabled/disabled as specified.

b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.

3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

 © 1997-2013 Microchip Technology Inc.

15.5 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS
2. TppS

T	
F Frequency	T Time

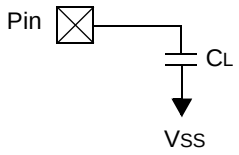
Lowercase letters (pp) and their meanings:

pp	
2 to	mc $\overline{\text{MCLR}}$
ck CLKOUT	osc oscillator
cy cycle time	os OSC1
drt device reset timer	t0 T0CKI
io I/O port	wdt watchdog timer

Uppercase letters and their meanings:

S	
F Fall	P Period
H High	R Rise
I Invalid (Hi-impedance)	V Valid
L Low	Z Hi-impedance

FIGURE 15-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54A



C_L = 50 pF for all pins and OSC2 for RC modes

0 -15 pF for OSC2 in XT, HS or LP modes when external clock is used to drive OSC1

 © 1997-2013 Microchip Technology Inc.

15.6 Timing Diagrams and Specifications

FIGURE 15-2: EXTERNAL CLOCK TIMING - PIC16C54A

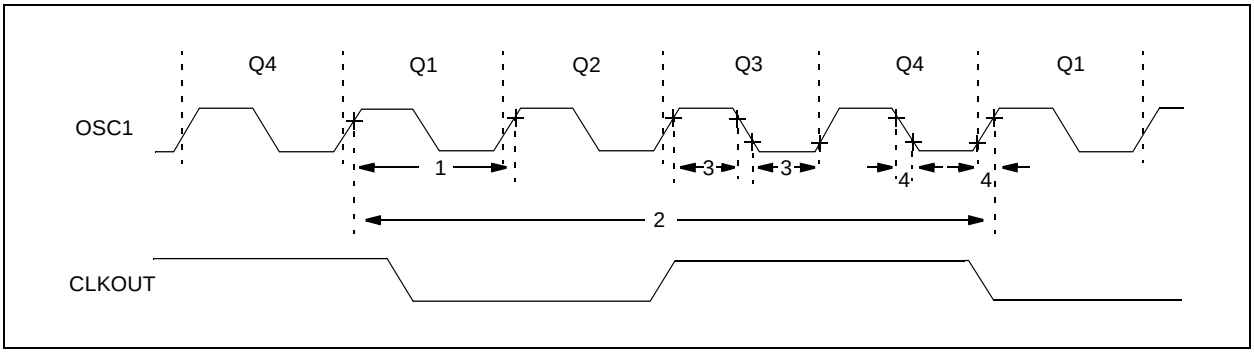


TABLE 15-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54A

AC Characteristics		Standard Operating Conditions (unless otherwise specified) Operating Temperature 0°C ≤ TA ≤ +70°C for commercial –40°C ≤ TA ≤ +85°C for industrial –20°C ≤ TA ≤ +85°C for industrial - PIC16LV54A-02I –40°C ≤ TA ≤ +125°C for extended					
Param No.	**Symbol**	**Characteristic**	**Min**	**Typ†**	**Max**	**Units**	**Conditions**
	FOSC	External CLKIN Frequency(1)	DC	—	4.0	MHz	XT osc mode
			DC	—	2.0	MHz	XT osc mode (PIC16LV54A)
			DC	—	4.0	MHz	HS osc mode (04)
			DC	—	10	MHz	HS osc mode (10)
			DC	—	20	MHz	HS osc mode (20)
			DC	—	200	kHz	LP osc mode
		Oscillator Frequency(1)	DC	—	4.0	MHz	RC osc mode
			DC	—	2.0	MHz	RC osc mode (PIC16LV54A)
			0.1	—	4.0	MHz	XT osc mode
			0.1	—	2.0	MHz	XT osc mode (PIC16LV54A)
			4.0	—	4.0	MHz	HS osc mode (04)
			4.0	—	10	MHz	HS osc mode (10)
			4.0	—	20	MHz	HS osc mode (20)
			5.0	—	200	kHz	LP osc mode

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.
When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

FIGURE 16-5: TYPICAL IPD VS. VDD, WATCHDOG DISABLED (25°C)

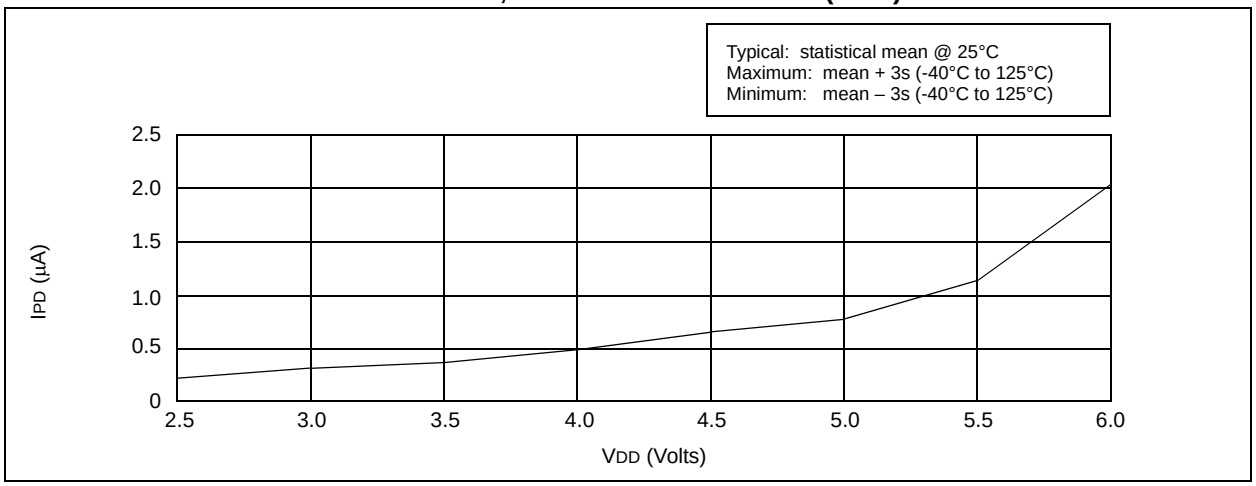
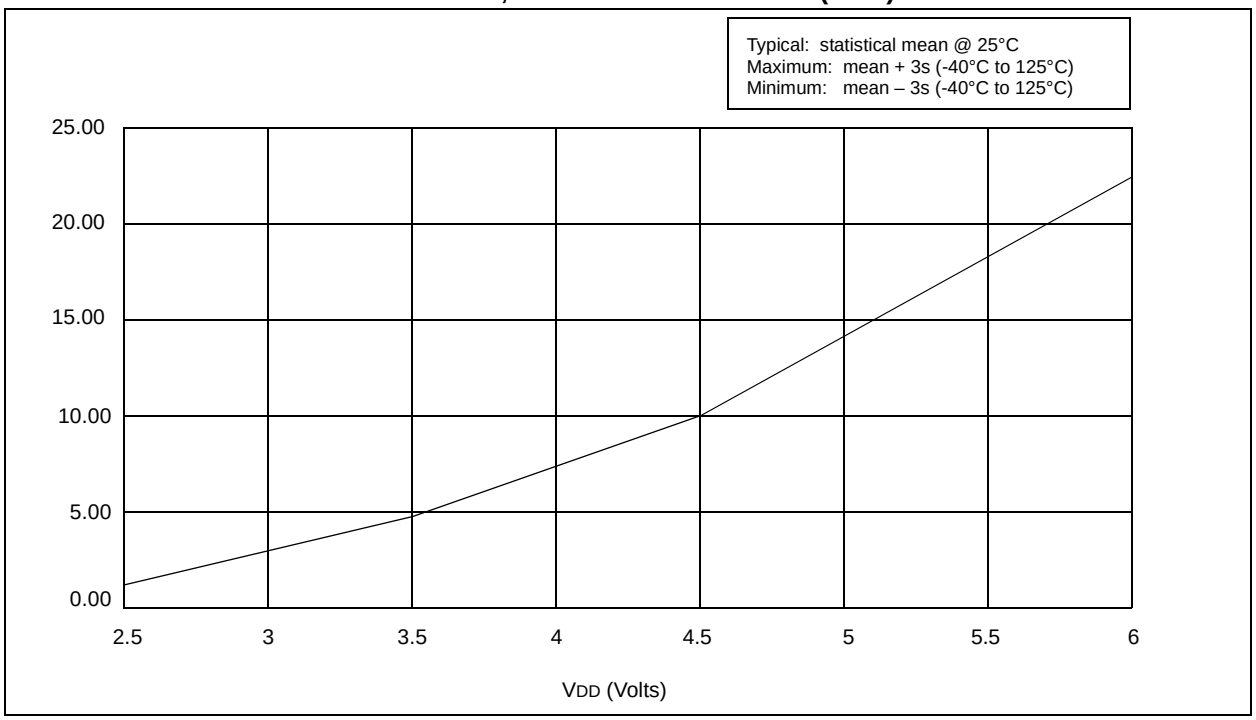


FIGURE 16-6: TYPICAL IPD VS. VDD, WATCHDOG ENABLED (25°C)



 © 1997-2013 Microchip Technology Inc.

FIGURE 16-7: VTH (INPUT THRESHOLD VOLTAGE) OF I/O PINS - VDD

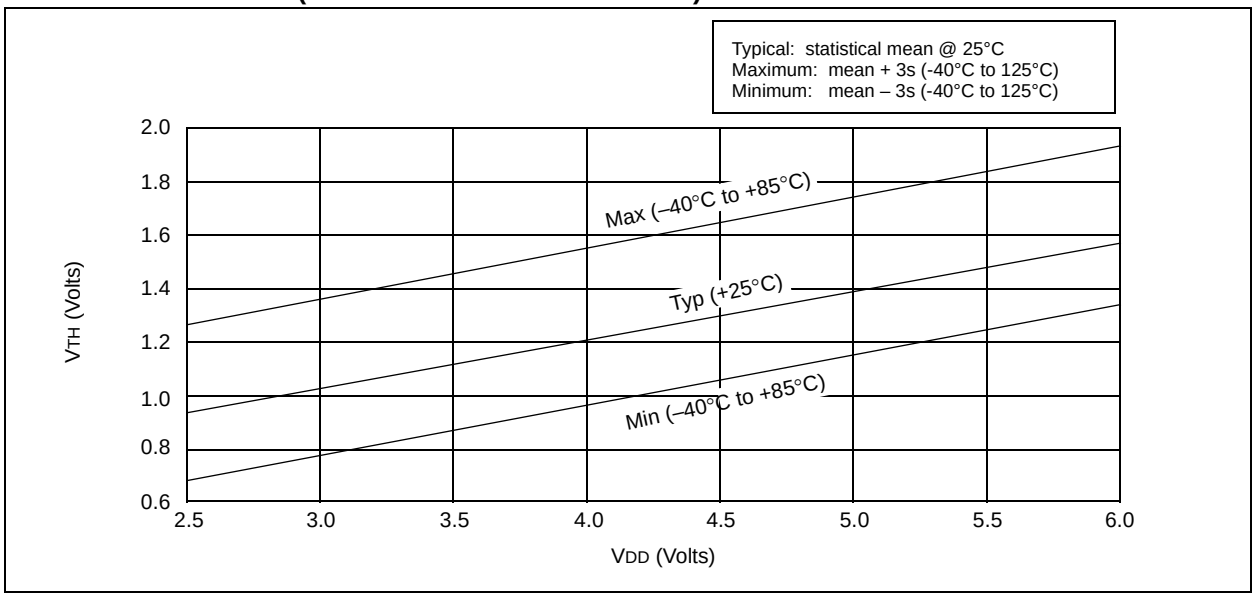


FIGURE 16-8: VTH (INPUT THRESHOLD VOLTAGE) OF OSC1 INPUT (IN XT, HS, AND LP MODES) vs. VDD

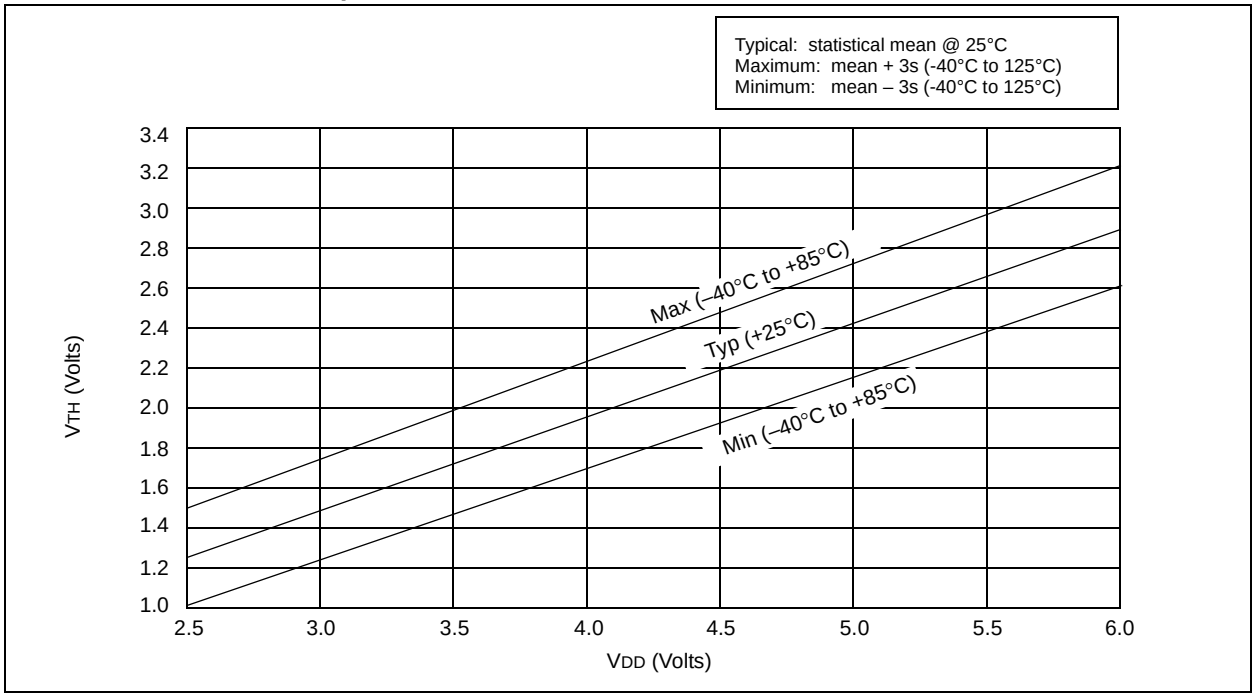
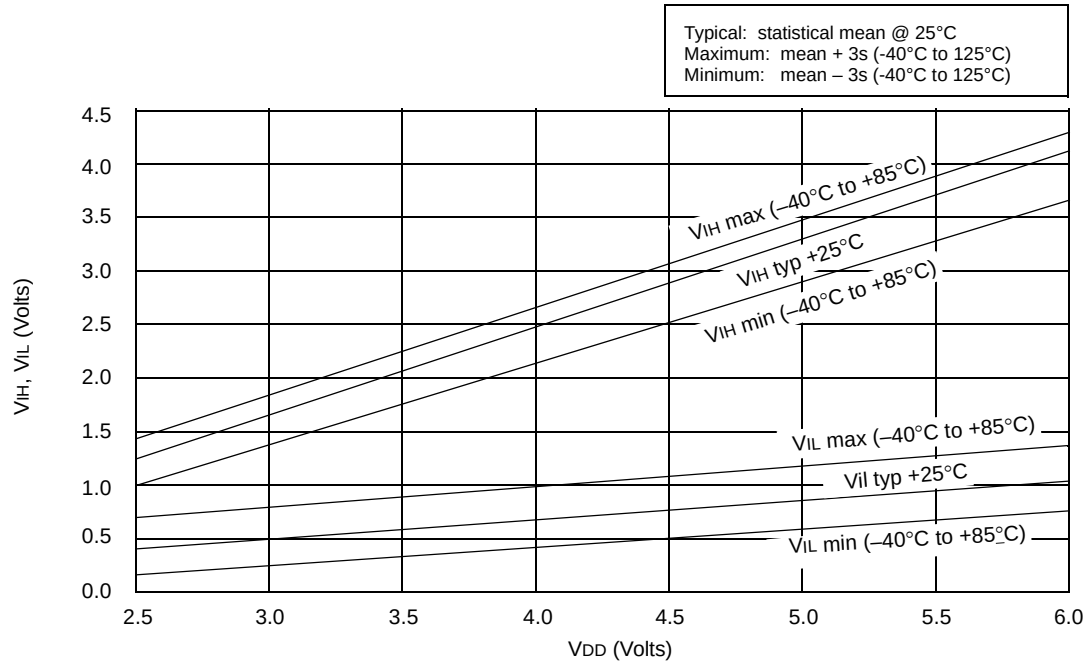


FIGURE 16-9: VIH, VIL OF $\overline{\text{MCLR}}$, T0CKI AND OSC1 (IN RC MODE) vs. VDD



Note: These input pins have Schmitt Trigger input buffers.

 © 1997-2013 Microchip Technology Inc.

FIGURE 16-20: PORTA, B AND C I_{OH} vs. V_{OH}, V_{DD} = 3V

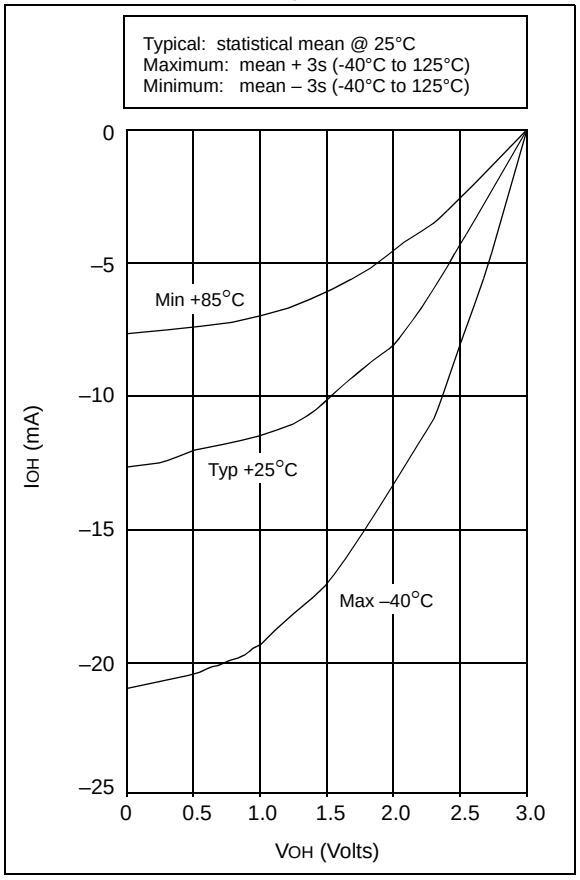
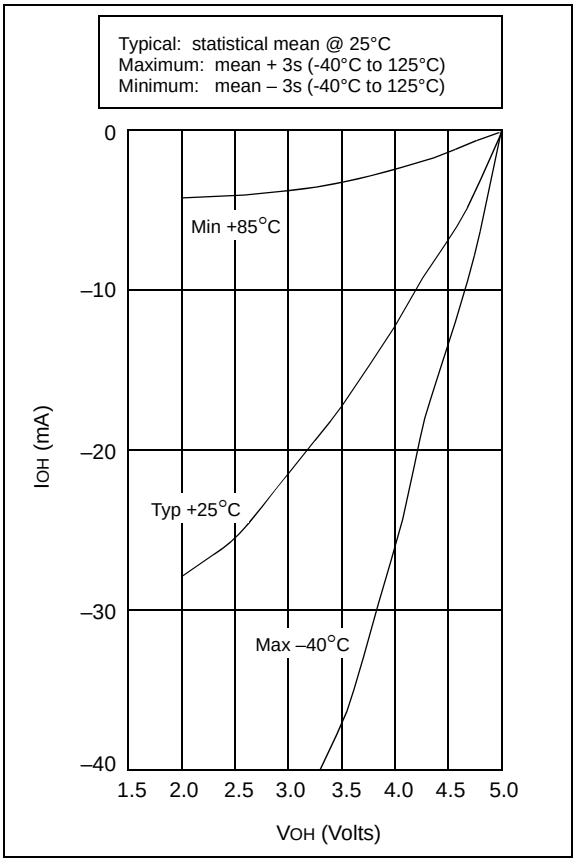


FIGURE 16-21: PORTA, B AND C I_{OH} vs. V_{OH}, V_{DD} = 5V



 © 1997-2013 Microchip Technology Inc.

FIGURE 18-2: TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 20 pF, 25°C

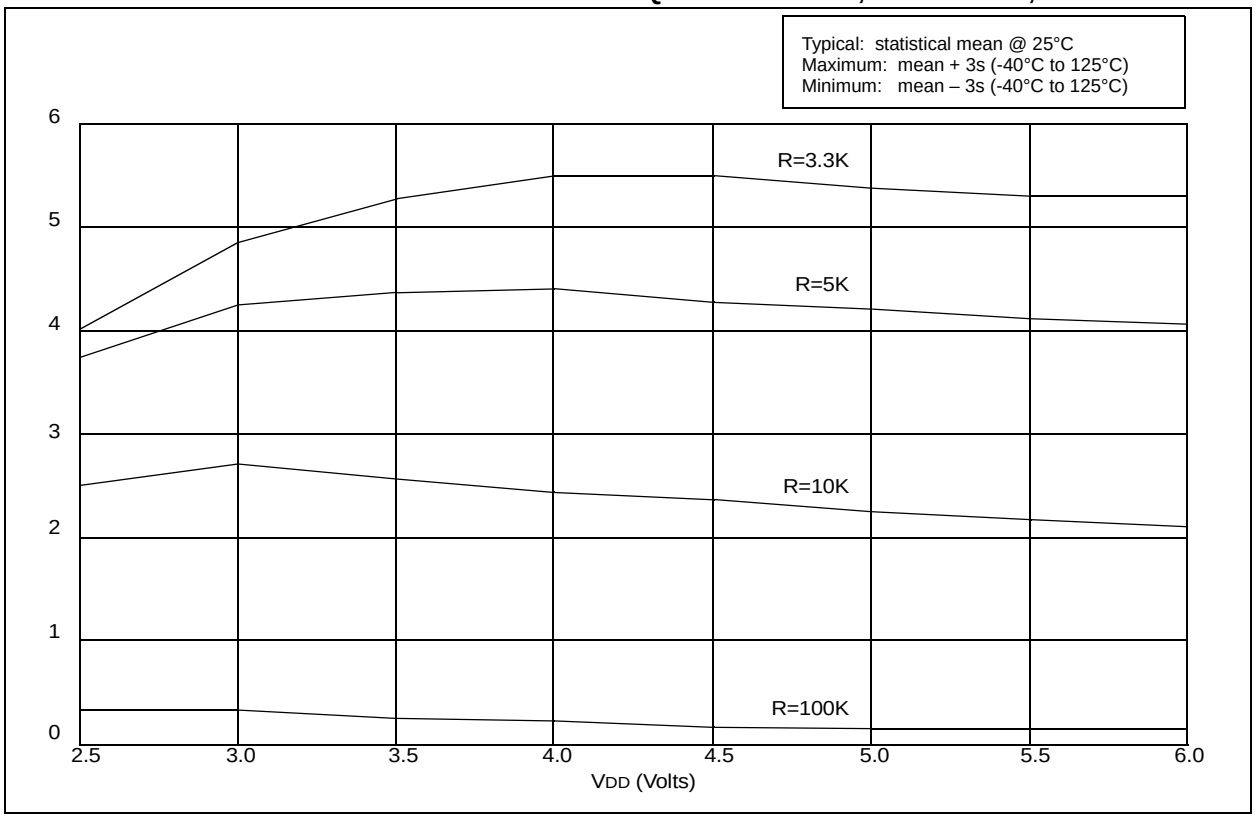
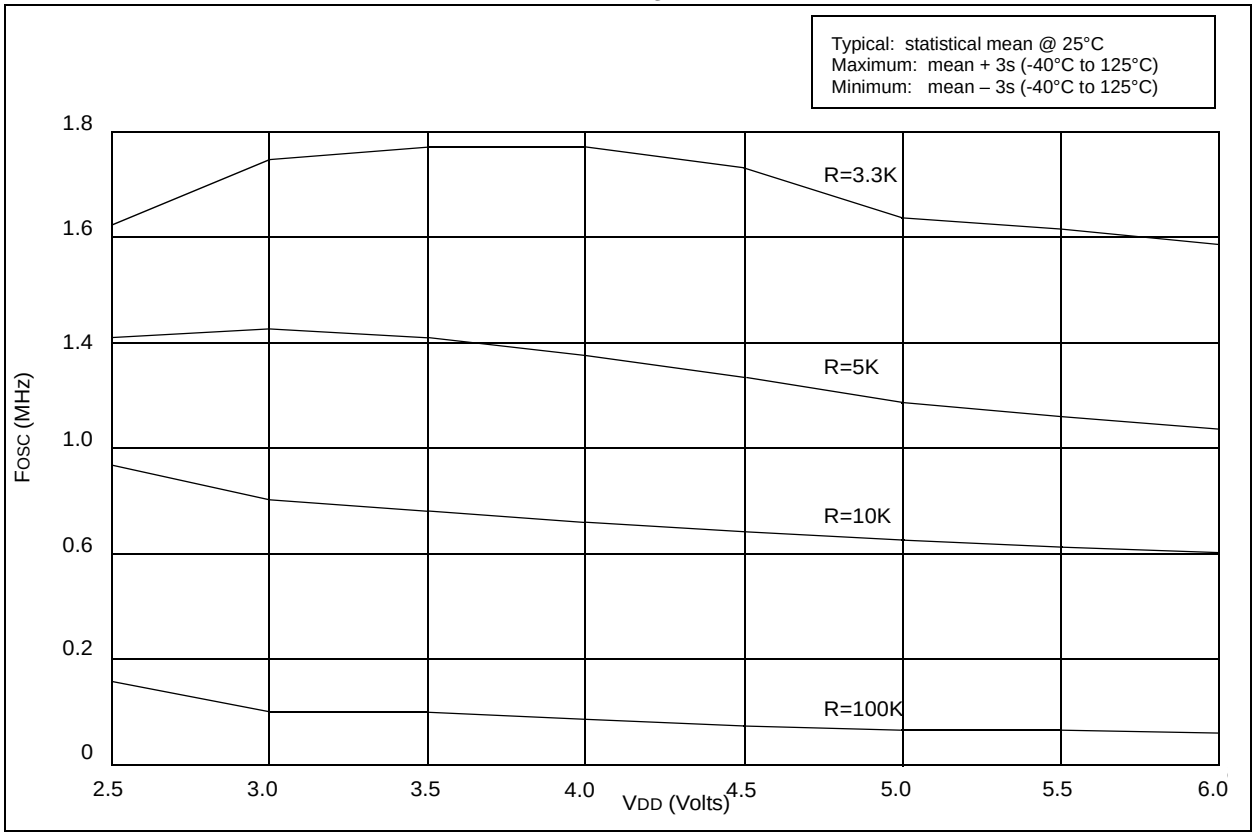
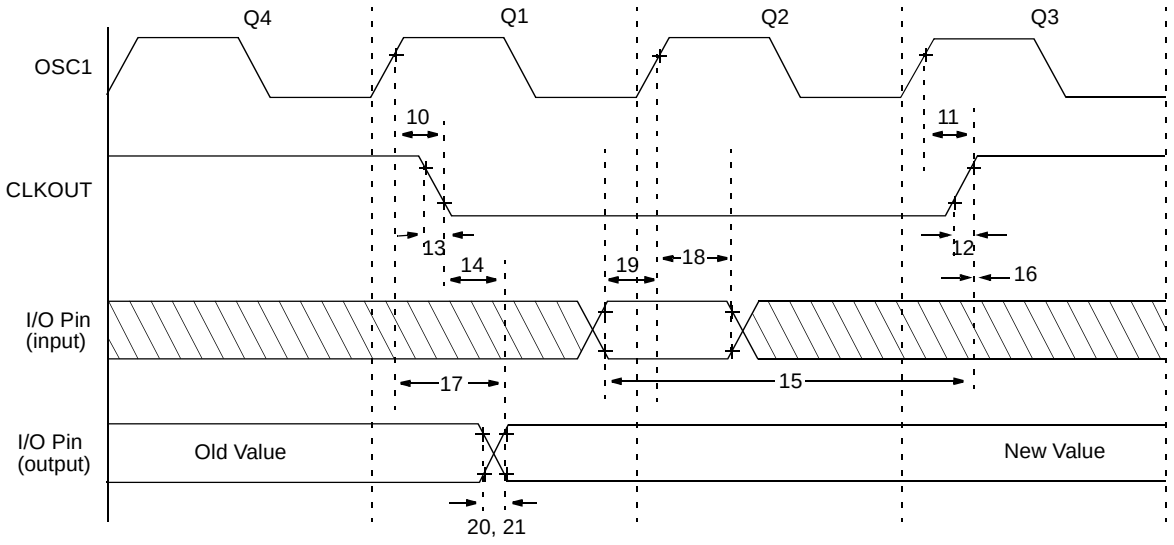


FIGURE 18-3: TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 100 pF, 25°C



 © 1997-2013 Microchip Technology Inc.

FIGURE 19-4: CLKOUT AND I/O TIMING - PIC16C5X-40



Note: Refer to Figure 19-2 for load conditions.

TABLE 19-2: CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C5X-40

AC Characteristics		**Standard Operating Conditions (unless otherwise specified)** Operating Temperature 0°C ≤ TA ≤ +70°C for commercial				
Param No.	**Symbol**	**Characteristic**	**Min**	**Typ†**	**Max**	**Units**
10	TosH2ckL	OSC1↑ to CLKOUT↓ **(1,2)**	—	15	30**	ns
11	TosH2ckH	OSC1↑ to CLKOUT↑ **(1,2)**	—	15	30**	ns
12	TckR	CLKOUT rise time **(1,2)**	—	5.0	15**	ns
13	TckF	CLKOUT fall time **(1,2)**	—	5.0	15**	ns
14	TckL2ioV	CLKOUT↓ to Port out valid **(1,2)**	—	—	40**	ns
15	TioV2ckH	Port in valid before CLKOUT↑ **(1,2)**	0.25 TCY+30*	—	—	ns
16	TckH2ioI	Port in hold after CLKOUT↑ **(1,2)**	0*	—	—	ns
17	TosH2ioV	OSC1↑ (Q1 cycle) to Port out valid **(2)**	—	—	100	ns
18	TosH2ioI	OSC1↑ (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—	—	ns
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns
20	TioR	Port output rise time **(2)**	—	10	25**	ns
21	TioF	Port output fall time **(2)**	—	10	25**	ns

* These parameters are characterized but not tested.

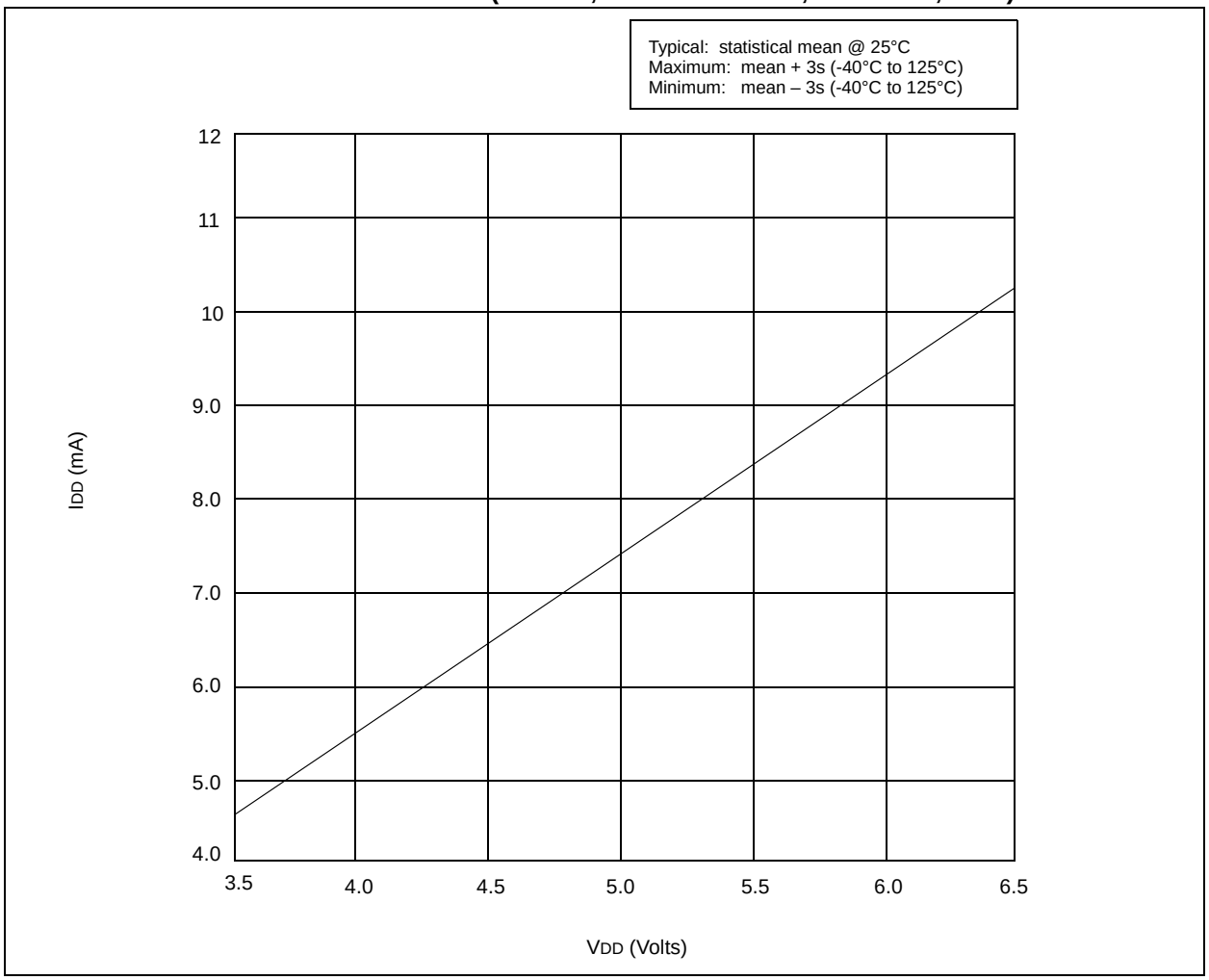
** These parameters are design targets and are not tested. No characterization data available at this time.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x TOSC.

2: Refer to Figure 19-2 for load conditions.

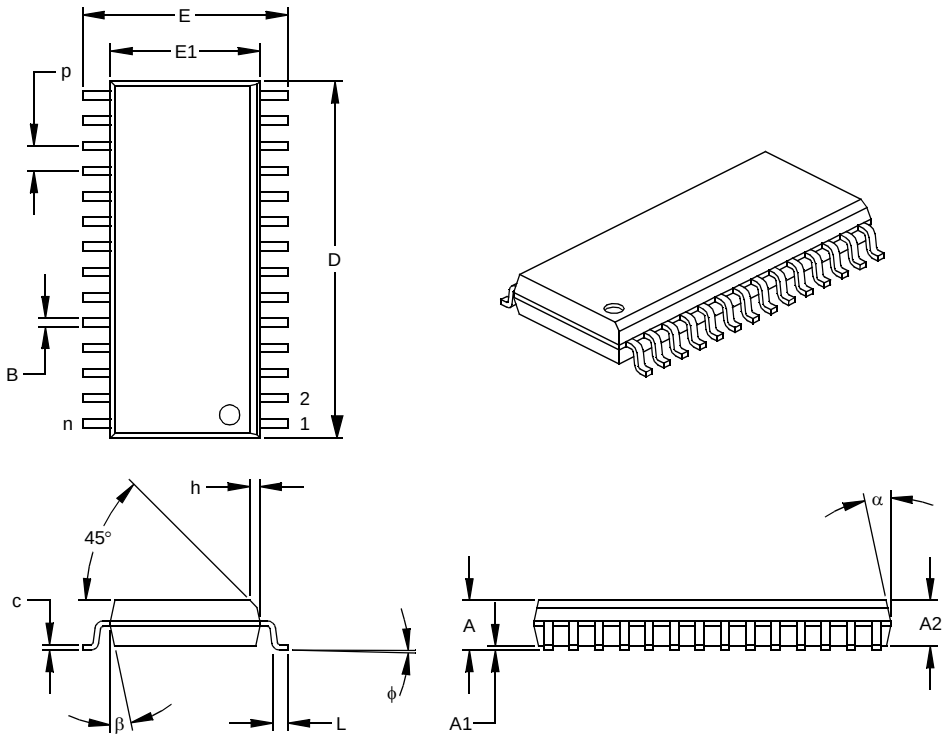
FIGURE 20-6: TYPICAL IDD vs. VDD (40 MHZ, WDT DISABLED, HS MODE, 70°C)



 © 1997-2013 Microchip Technology Inc.

28-Lead Plastic Small Outline (SO) – Wide, 300 mil (SOIC)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		INCHES*			MILLIMETERS		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		28			28	
Pitch	p		.050			1.27	
Overall Height	A	.093	.099	.104	2.36	2.50	2.64
Molded Package Thickness	A2	.088	.091	.094	2.24	2.31	2.39
Standoff §	A1	.004	.008	.012	0.10	0.20	0.30
Overall Width	E	.394	.407	.420	10.01	10.34	10.67
Molded Package Width	E1	.288	.295	.299	7.32	7.49	7.59
Overall Length	D	.695	.704	.712	17.65	17.87	18.08
Chamfer Distance	h	.010	.020	.029	0.25	0.50	0.74
Foot Length	L	.016	.033	.050	0.41	0.84	1.27
Foot Angle Top	ϕ	0	4	8	0	4	8
Lead Thickness	c	.009	.011	.013	0.23	0.28	0.33
Lead Width	B	.014	.017	.020	0.36	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

* Controlling Parameter
§ Significant Characteristic

Notes:
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010” (0.254mm) per side.
JEDEC Equivalent: MS-013
Drawing No. C04-052